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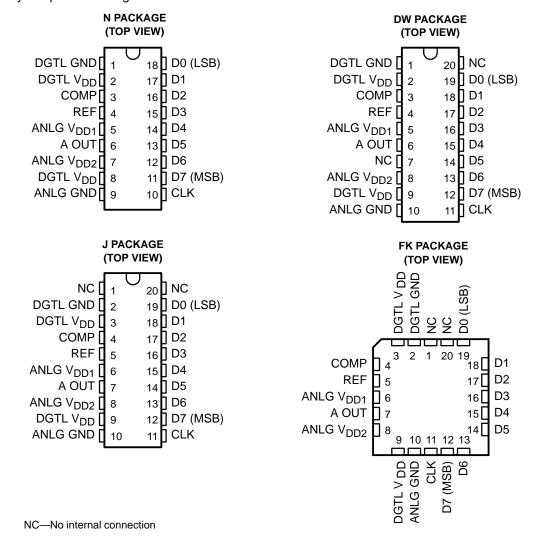
- 8-Bit Resolution
- ±0.2% Linearity
- **Maximum Conversion Rate** 30 MHz Typ 20 MHz Min
- **Analog Output Voltage Range** V_{DD} to $V_{DD} - 1 V$

- TTL Digital Input Voltage
- 5-V Single Power-Supply Operation
- Low Power Consumption . . . 80 mW Typ
- Interchangeable With Fujitsu MB40778

description

The TLC5602x devices are low-power, ultra-high-speed video, digital-to-analog converters that use the LinEPIC™ 1-µm CMOS process. The TLC5602x converts digital signals to analog signals at a sampling rate of dc to 20 MHz. Because of high-speed operation, the TLC5602x devices are suitable for digital video applications such as digital television, video processing with a computer, and radar-signal processing.

The TLC5602C is characterized for operation from 0°C to 70°C. The TLC5602M is characterized over the full military temperature range of -55°C to 125°C.



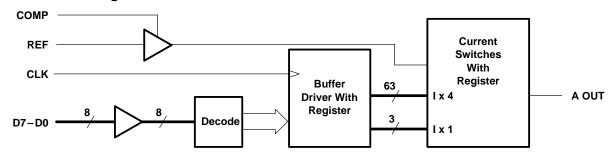
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AVAILABLE OPTIONS

PACKAGE									
TA	WIDE-BODY SMALL OUTLINE (DW)	CERAMIC CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)					
0°C to 70°C	TLC5602CDW			TLC5602CN					
-55°C to 125°C		TLC5602MFK	TLC5602MJ						

functional block diagram

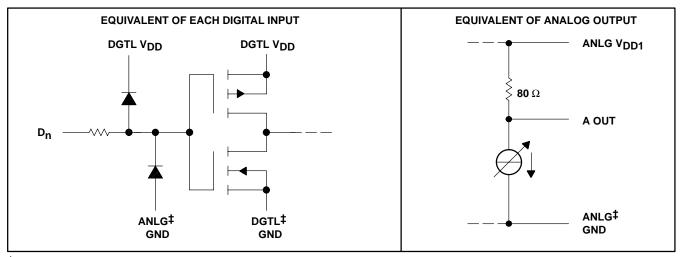


FUNCTION TABLE

STEP	DIGITAL INPUTS							OUTPUT	
	D7	D6	D5	D4	D3	D2	D1	D0	VOLTAGE [†]
0	L	L	L	L	L	L	L	L	3.980 V
1	L	L	L	L	L	L	L	Н	3.984 V
					1				1
127	L	Н	Н	Н	Н	Н	Н	Н	4.488 V
128	Н	L	L	L	L	L	L	L	4.492 V
129	Н	L	L	L	L	L	L	Н	4.496 V
									1
254	Н	Н	Н	Н	Н	Н	Н	L	4.996 V
255	Н	Н	Н	Н	Н	Н	Н	Н	5.000 V

 \dagger V_{DD} = 5 V and V_{ref} = 4.02 V

schematics of equivalent input and output



[‡] ANLG GND and DGTL GND do not connect internally and should be tied together as close to the device terminals as possible.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, ANLG V _{DD} , DGTL V _{DD}	0.5 V to 7 V
Digital input voltage range, V _I	0.5 V to 7 V
Analog reference voltage range, V _{ref}	
Operating free-air temperature range, T _A : TLC5602C	0°C to 70°C
TLC5602M	–55°C to 125°C
Storage temperature range, T _{stq}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			MIN	NOM	MAX	UNIT	
Supply voltage, V _{DD}			4.75	5	5.25	V	
Analog reference voltage, V _{ref}				4	4.2	V	
High-level input voltage, V _{IH}			2			V	
Low-level input voltage, V _{IL}					8.0	V	
Pulse duration, CLK high or low, tw			25			ns	
Setup time, data before CLK↑, t _{SU}			16.5			ns	
Hold time, data after CLK↑, th						ns	
Phase compensation capacitance, Ccor	Phase compensation capacitance, C _{comp} (see Note 1)					μF	
Load resistance, R _L			75			Ω	
Operating free air temperature Te	TLC5602C		0		70	°C	
Operating free-air temperature,T _A	TLC5602M		-55		125		

NOTE 1: The phase compensation capacitor should be connected between COMP and ANLG GND.



TLC5602C, TLC5602M VIDEO 8-BIT DIGITAL-TO-ANALOG CONVERTERS

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER			TEST CONDITIONS			MIN	TYP‡	MAX	UNIT
lн	High-level input current	Digital	V _I = 5 V					±1	μΑ
I _I L	Low-level input current	inputs	V _I = 0 V				±1	μΑ	
I _{ref}	Input reference current		V _{ref} = 4 V	V _{ref} = 4 V				10	μΑ
V_{FS}	Full-scale analog output vo	$V_{DD} = 5 \text{ V}, \qquad V_{ref} = 4.02 \text{ V}$			V _{DD} -15	V_{DD}	V _{DD} +15	mV	
	V _{ZS} Zero-scale analog output voltage		$V_{DD} = 5 \text{ V},$ $V_{ref} = 4.02 \text{ V},$ $T_{A} = \text{full range}$.,	TLC5602C	3.919	3.98	4.042	
Vzs				TLC5602M	3.919	3.98	4.042	V	
			TA = Tall Tallges		TLC5602M	3.919	3.98	4.062	
_	r _O Output resistance		$T_A = 25^{\circ}C$ TLC5602C		60	80	120	Ω	
10			T _A = full range§ TLC5602M						
Ci	Input capacitance		$f_{clock} = 1 \text{ MHz}, T_A = 25^{\circ}\text{C}$				15	·	pF
I_{DD}	Supply current	$f_{clock} = 20 \text{ MHz}, V_{ref} = V_{DD} - 0.95 \text{ V}$				16	25	mA	

[‡] All typical values are at $V_{DD} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

operating characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONE	MIN	TYP†	MAX	UNIT	
	-	T _A = full range‡	TLC5602C			±0.2%	
E _{L(adj)}		T _A = 25°C	TLC5602M			±0.2%	
		T _A = full range‡	1 LC3002IVI			±0.4%	
EL	Linearity error, end point				±0.15%		
E _D	Linearity error, differential					±0.2%	
G _{diff}	Differential gain	NTSC 40-IRE modulated ramp,			0.7%		
fdiff	Differential phase	$f_{clock} = 14.3 \text{ MHz}, Z_L \ge 75 \text{ k}\Omega$			0.4°		
t _{pd}	Propagation delay time, CLK to analog output	C _L = 10 pF			25		ns
t _S	Settling time to within 1/2 LSB	C _L = 10 pF			30	•	ns

[†] All typical values are at $V_{DD} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.



[§] Full range for the TLC5602C is 0°C to 70°C, and full range for the TLC5602M is -55°C to 125°C.

[‡] Full range for the TLC5602C is 0°C to 70°C, and full range for the TLC5602M is -55°C to 125°C.

PARAMETER MEASUREMENT INFORMATION

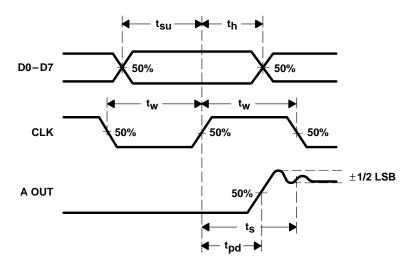
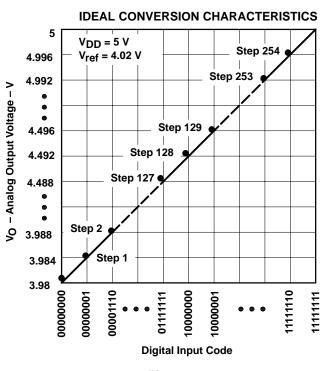


Figure 1. Voltage Waveforms

TYPICAL CHARACTERISTICS



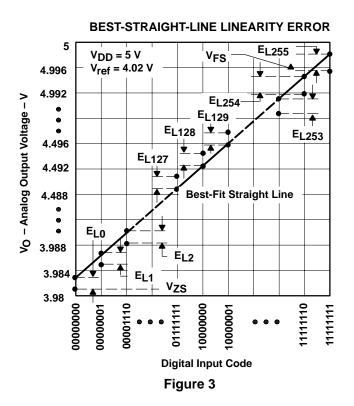


ZERO-SCALE OUTPUT VOLTAGE

FREE-AIR TEMPERATURE 4.02 $V_{DD} = 5 V$ V_{ref} = 4.02 V 4.01 Vzs - Zero-Scale Output Voltage - V See Note A 3.99 3.98 3.97 3.96 3.95 3.94 3.93 - 55 - 35 - 15 5 25 45 65 85 105 125 T_A – Free-Air Temperature – $^{\circ}$ C

NOTE A: V_{ref} is relative to ANLG GND. V_{DD} is the voltage between ANLG V_{DD} and DGTL V_{DD} tied together and ANLG GND and DGTL GND tied together.

Figure 4



OUTPUT RESISTANCE vs FREE-AIR TEMPERATURE

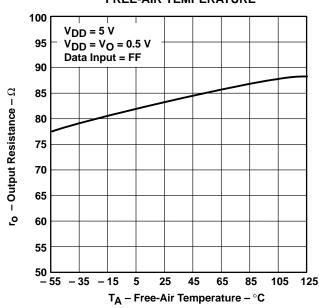
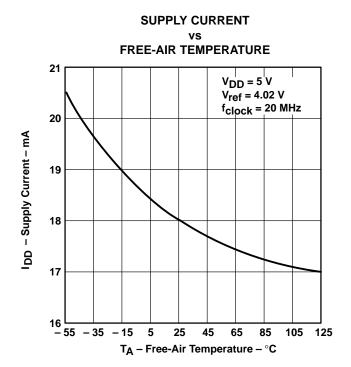


Figure 5



ZERO-SCALE OUTPUT VOLTAGE

TYPICAL CHARACTERISTICS



REFERENCE VOLTAGE $V_{DD} = 5 \text{ V}$ $T_A = 25^{\circ}C$ 4.8 See Note A Vzs - Zero-Scale Output Voltage - V 4.6 4.4 4.2 3.8

NOTE A: V_{ref} is relative to ANLG GND. V_{DD} is the voltage between ANLG V_{DD} and DGTL V_{DD} tied together and ANLG GND and DGTL GND tied together.

4.2

V_{ref} - Reference Voltage - V

4.4

4.6

4.8

5

4

Figure 6 Figure 7

3.6

3.4 3.4

3.6

3.8

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APPLICATION INFORMATION

The following design recommendations benefit the TLC5602 user:

- Physically separate and shield external analog and digital circuitry as much as possible to reduce system noise.
- Use RF breadboarding or RF printed-circuit-board (PCB) techniques throughout the evaluation and production process.
- Since ANLG GND and DGTL GND are not connected internally, these terminals need to be connected
 externally. With breadboards, these ground lines should connect to the power-supply ground through
 separate leads with proper supply bypassing. A good method is to use a separate twisted pair for the analog
 and digital supply lines to minimize noise pickup.
 - Use wide ground leads or a ground plane on the PCB layouts to minimize parasitic inductance and resistance. The ground plane is the better choice for noise reduction.
- ANLG V_{DD} and DGTL V_{DD} are also separated internally, so they must connect externally. These external
 PCB leads should also be made as wide as possible. Place a ferrite bead or equivalent inductance in series
 with ANLG V_{DD} and the decoupling capacitor as close to the device terminals as possible before the ANLG
 V_{DD} and DGTL V_{DD} leads are connected together on the board.
- Decouple ANLG V_{DD} to ANLG GND and DGTL V_{DD} to DGTL GND with a 1-μF and 0.01-μF capacitor, respectively, as close as possible to the appropriate device terminals. A ceramic chip capacitor is recommended for the 0.01-μF capacitor.
- Connect the phase compensation capacitor between COMP and ANLG GND with as short a lead-in as possible.
- The no-connection (NC) terminals on the small-outline package should be connected to ANLG GND.
- Shield ANLG V_{DD}, ANLG GND, and A OUT from the high-frequency terminals CLK and D7-D0. Place ANLG GND traces on both sides of the A OUT trace on the PCB.



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Texas Instruments Post Office Box 655303 Dallas, Texas 75265

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